

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

## TC7WH245FU, TC7WH245FK

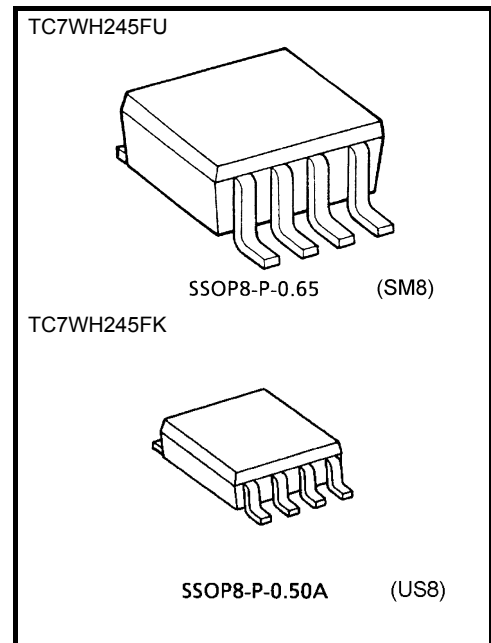
Dual Bus Transceiver

### FEATURES

- High Speed :  $t_{pd} = 4.0 \text{ ns (typ.)}$   
at  $V_{CC} = 5 \text{ V}$ ,  $C_L = 15 \text{ pF}$
- Low Power Dissipation :  $I_{CC} = 2 \mu\text{A (max)}$  at  $T_a = 25^\circ\text{C}$
- High Noise Immunity :  $V_{NIH} = V_{NIL} = 28\% V_{CC} \text{ (min)}$
- Balanced Propagation Delays:  $t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range:  $V_{CC} \text{ (opr)} = 2 \text{ to } 5.5 \text{ V}$
- Low Noise :  $V_{OLP} = 0.8 \text{ V (max)}$

### APPLICATION NOTES

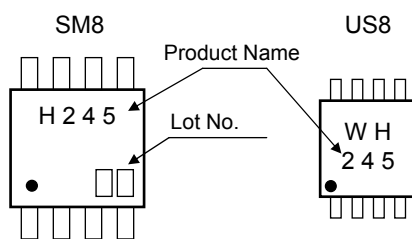
- 1) Do not apply a signal to any bus terminal when it is in the output mode. Damage may result.
- 2) All floating (high impedance) bus terminals must have their input levels fixed by means of pull up or pull down resistors.
- 3) A parasitic diode is formed between the bus and  $V_{CC}$  terminals. Therefore bus terminal can not be used to interface 5V to 3V systems directly.



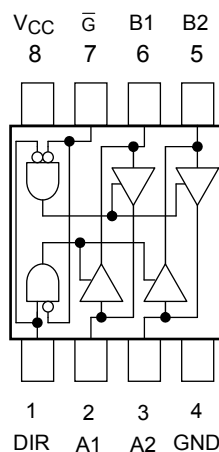
Weight

- SSOP8-P-0.65 : 0.02 g (typ.)
- SSOP8-P-0.50A : 0.01 g (typ.)

### Marking



### Pin Assignment (top view)



Start of commercial production  
1999-12

## Absolute Maximum Ratings (Ta = 25°C)

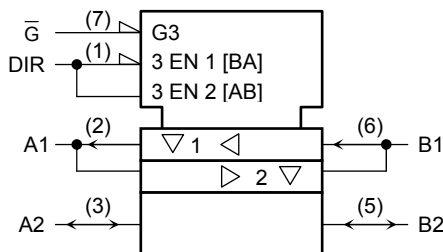
Characteristic	Symbol	Rating	Unit
Supply Voltage	V <sub>CC</sub>	-0.5 to 7	V
DC Input Voltage	V <sub>IN</sub>	-0.5 to 7	V
DC Output Voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input Diode Current	I <sub>IK</sub>	-20	mA
Output Diode Current	I <sub>OK</sub>	±20 (Note 1)	mA
DC Output Current	I <sub>OUT</sub>	±25	mA
DC Vcc/Ground Current	I <sub>CC</sub>	±50	mA
Power Dissipation	P <sub>D</sub>	300(SM8) 200(US8)	mW
Storage Temperature	T <sub>stg</sub>	-65 to 150	°C
Lead Temperature(10s)	T <sub>L</sub>	260	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V<sub>OUT</sub> < GND, V<sub>OUT</sub> > V<sub>CC</sub>

## IEC Logic Symbol



## Truth Table

Input		Function		Output
$\bar{G}$	DIR	A BUS	B BUS	
L	L	OUTPUT	INPUT	A = B
L	H	INPUT	OUTPUT	B = A
H	X	High impedance		Z

X: Don't care

Z: High impedance

## Operating Ranges

Characteristic	Symbol	Rating	Unit
Supply Voltage	V <sub>CC</sub>	2 to 5.5	V
Input Voltage	V <sub>IN</sub>	0 to 5.5	V
Output Voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating Temperature	T <sub>opr</sub>	-40 to 85	°C
Input Rise and Fall Time	dt/dv	0 to 100 (V <sub>CC</sub> = 3.3 ± 0.3 V)	ns/V
		0 to 20 (V <sub>CC</sub> = 5.0 ± 0.5 V)	

## Electrical Characteristics

### DC Characteristics

Characteristic	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit		
				V <sub>CC</sub> (V)	Min	Typ.	Max	Min		Max	
High-Level Input Voltage	V <sub>IH</sub>	—		2.0	1.5	—	—	1.5	V		
				3.0 to 5.5	V <sub>CC</sub> × 0.7	—	—	V <sub>CC</sub> × 0.7		—	
Low-Level Input Voltage	V <sub>IL</sub>	—		2.0	—	—	0.5	—	V		
				3.0 to 5.5	—	—	V <sub>CC</sub> × 0.3	—		V <sub>CC</sub> × 0.3	
High-Level Output Voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		I <sub>OH</sub> = -50 μA	2.0	1.9	2.0	—	1.9	V	
					3.0	2.9	3.0	—	2.9		—
					4.5	4.4	4.5	—	4.4		—
				I <sub>OH</sub> = -4 mA		3.0	2.58	—	—		2.48
I <sub>OH</sub> = -8 mA		4.5	3.94	—	—	3.80	—				
Low-Level Output Voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		I <sub>OL</sub> = 50 μA	2.0	—	0.0	0.1	—	V	
					3.0	—	0.0	0.1	—		0.1
					4.5	—	0.0	0.1	—		0.1
				I <sub>OL</sub> = 4 mA		3.0	—	—	0.36		—
I <sub>OL</sub> = 8 mA		4.5	—	—	0.36	—	0.44				
3-State Output Off-State Current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND		5.5	—	—	±0.25	—	±2.50	μA	
Input Leakage Current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	—	—	±0.1	—	±1.0	μA	
Quiescent Sply Current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	—	—	2.0	—	20.0	μA	

## AC Characteristics (Input: $t_r = t_f = 3$ ns)

Characteristic	Symbol	Test Condition	Ta = 25°C			Ta = -40 to 85°C		Unit		
			VCC (V)	CL (pF)	Min	Typ.	Max		Min	Max
Propagation Delay Time	$t_{pLH}$	—	$3.3 \pm 0.3$	15	—	5.8	8.4	1.0	10.0	ns
				50	—	8.3	11.9	1.0	13.5	
	$t_{pHL}$		$5.0 \pm 0.5$	15	—	4.0	5.5	1.0	6.5	
				50	—	5.5	7.5	1.0	8.5	
3-State Output Enable Time	$t_{pZL}$	$R_L = 1$ k $\Omega$	$3.3 \pm 0.3$	15	—	8.5	13.2	1.0	15.5	ns
				50	—	11.0	16.7	1.0	19.0	
	$t_{pZH}$		$5.0 \pm 0.5$	15	—	5.8	8.5	1.0	10.0	
				50	—	7.3	10.6	1.0	12.0	
3-State Output Disable Time	$t_{pLZ}$	$R_L = 1$ k $\Omega$	$3.3 \pm 0.3$	50	—	11.5	15.8	1.0	18.0	ns
				$t_{pHZ}$	50	—	7.0	9.7	1.0	
Output to Output Skew	$t_{osLH}$	(Note 2)	$3.3 \pm 0.3$	50	—	—	1.5	—	1.5	ns
				$t_{osHL}$	50	—	—	1.0	—	
Input Capacitance	$C_{IN}$	DIR, $\bar{G}$	—	—	—	4	10	—	10	pF
Bus Input Capacitance	$C_{I/O}$	An, Bn	—	—	—	8	—	—	—	pF
Power Dissipation Capacitance	$C_{PD}$	(Note 3)	—	—	—	21	—	—	—	pF

Note 2: Parameter guaranteed by design.

$$t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|$$

Note 3:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

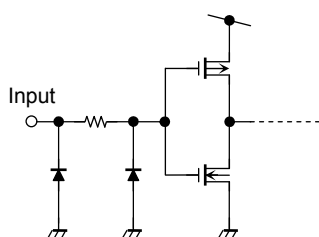
Average operating current can be obtained by the equation:

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 \text{ (per bit)}$$

## Noise Characteristics (Ta = 25°C, Input: $t_r = t_f = 3$ ns)

Characteristic	Symbol	Test Condition	VCC (V)	Typ.	Limit	Unit
			5.0			
Quiet Output Maximum Dynamic $V_{OL}$	$V_{OLP}$	$C_L = 50$ pF	5.0	0.5	0.8	V
Quiet Output Minimum Dynamic $V_{OL}$	$V_{OLV}$	$C_L = 50$ pF	5.0	-0.5	-0.8	V
Minimum High Level Dynamic Input Voltage	$V_{IHD}$	$C_L = 50$ pF	5.0	—	3.5	V
Maximum Low Level Dynamic Input Voltage	$V_{ILD}$	$C_L = 50$ pF	5.0	—	1.5	V

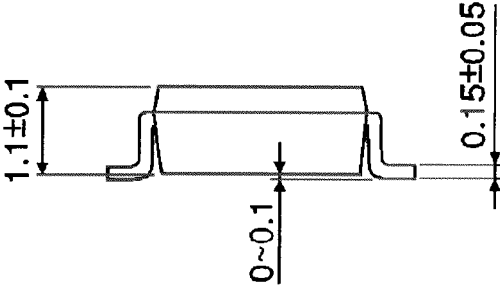
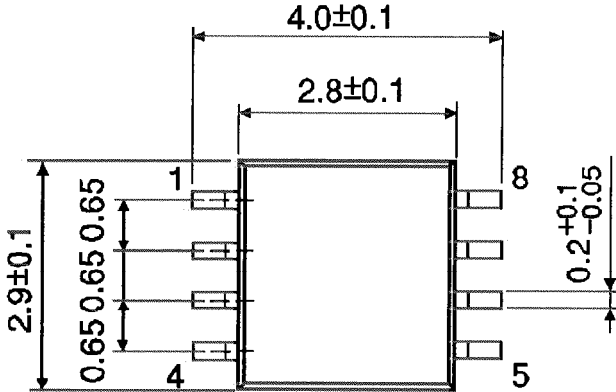
## Input Equivalent Circuit



**Package Dimensions**

SSOP8-P-0.65

Unit : mm

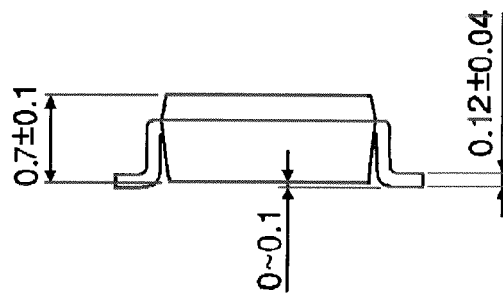
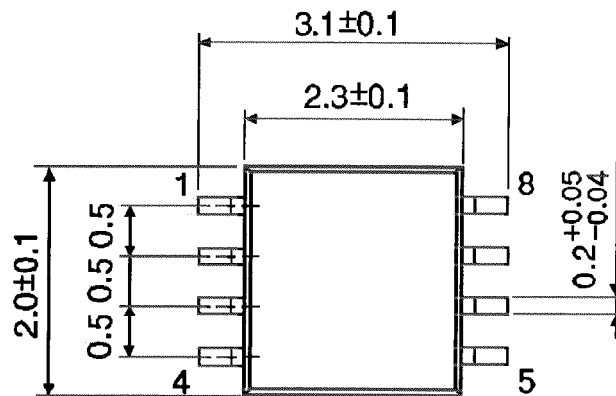


Weight: 0.02 g (Typ.)

## Package Dimensions

SSOP8-P-0.50A

Unit : mm



Weight: 0.01 g (Typ.)

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